## NSN 5961-01-080-5811

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-080-5811 **Inclosure Material:** Glass **Overall Length:** 0.375 inches **Terminal Length:** 1.062 inches **Overall Diameter:** 0.210 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 nonrepetitive peak reverse voltage and 30.0 repetitive peak reverse voltage and 21.0 reverse voltage, total rms **Current Rating Per Characteristic:** 3.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: